



1-Mbps QUAD DIGITAL ISOLATORS

Check for Samples: [ISO7241A-EP](#)

FEATURES

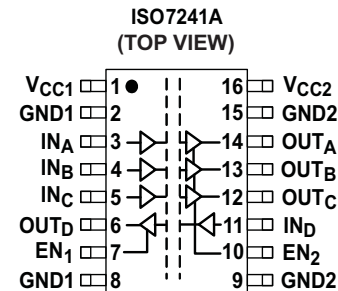
- 4000- V_{peak} Isolation, 560- V_{peak} V_{IORM}
 - UL 1577 , IEC 60747-5-2 (VDE 0884, Rev 2), IEC 61010-1, IEC 60950-1 and CSA Approved
- 4-kV ESD Protection
- Operates With 3.3-V or 5-V Supplies
- Typical 25-Year Life at Rated Working Voltage (See Application Note ([SLLA197](#)) and [Figure 10](#))
- High Electromagnetic Immunity (See Application Report ([SLLA181](#)))

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly/Test Site
- One Fabrication Site
- Available in Military ($-55^{\circ}\text{C}/125^{\circ}\text{C}$) Temperature Range⁽¹⁾
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability

APPLICATIONS

- Industrial Fieldbus
- Computer Peripheral Interface
- Servo Control Interface
- Data Acquisition



(1) Additional temperature ranges available - contact factory

DESCRIPTION

See the [Product Notification](#) section. The ISO7241A is a quad-channel digital isolator with multiple channel configurations and output enable functions. This device has logic input and output buffers separated by TI's silicon dioxide (SiO_2) isolation barrier. Used in conjunction with isolated power supplies, this device blocks high voltage, isolate grounds, and prevent noise currents from entering the local ground and interfering with or damaging sensitive circuitry.

The ISO7241A has three channels the same direction and one channel in opposition.

This device has TTL input thresholds and a noise-filter at the input that prevents transient pulses from being passed to the output of the device.

A periodic update pulse is sent across the barrier to ensure the proper dc level of the output. If this dc-refresh pulse is not received, the input is assumed to be unpowered or not being actively driven, and the failsafe circuit drives the output to a logic high state. (See ISO7240CF ([SLLS869](#)) or contact TI for a logic low failsafe option).

The ISO7241A may be powered from either 3.3-V or 5-V supplies on either side in any 3.3-V / 3.3-V, 5-V / 5-V, 5-V / 3.3-V, or 3.3-V / 5-V combination. Note that the signal input pins are 5-V tolerant regardless of the voltage supply level being used.

This device is characterized for operation over the ambient temperature range of -55°C to 125°C .



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

FUNCTION DIAGRAM

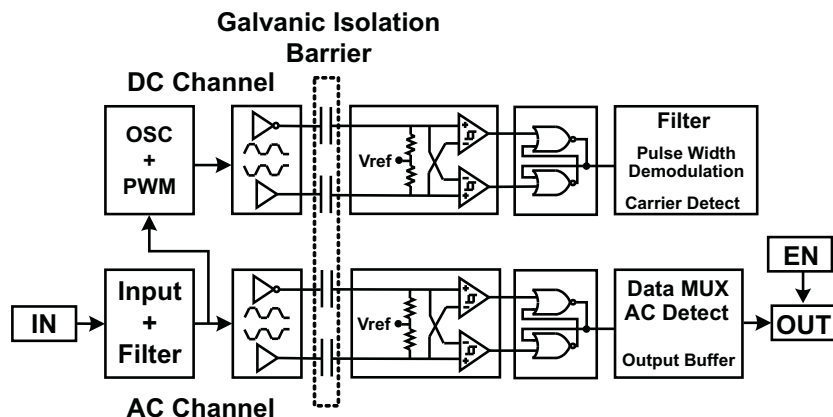


Table 1. Device Function Table⁽¹⁾

INPUT V_{CC}	OUTPUT V_{CC}	INPUT (IN)	OUTPUT ENABLE (EN)	OUTPUT (OUT)
PU	PU	H	H or Open	H
		L	H or Open	L
		X	L	Z
		Open	H or Open	H
PD	PU	X	H or Open	H
PD	PU	X	L	Z

(1) PU = Powered Up; PD = Powered Down ; X = Irrelevant; H = High Level; L = Low Level

Table 2. ORDERING INFORMATION⁽¹⁾

T_A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–55°C to 125°C	DW	Reel	ISO7241AMDWREP	ISO7241AM

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

(2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

					VALUE	UNIT
V _{CC}	Supply voltage ⁽²⁾ , V _{CC1} , V _{CC2}				−0.5 to 6	V
V _I	Voltage at IN, OUT, EN				−0.5 to 6	V
I _O	Output current				±15	mA
ESD	Electrostatic discharge	Human Body Model	JEDEC Standard 22, Test Method A114-C.01	All pins	±4	kV
		Field-Induced-Charged Device Model	JEDEC Standard 22, Test Method C101		±1	
		Machine Model	ANSI/ESDS5.2-1996		±200	V
T _J	Maximum junction temperature				170	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal and are peak voltage values.

RECOMMENDED OPERATING CONDITIONS

		MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage ⁽¹⁾ , V _{CC1} , V _{CC2}	3.15		5.5	V
I _{OH}	High-level output current			4	mA
I _{OL}	Low-level output current	–4			mA
t _{ui}	Input pulse width	1			μs
1/t _{ui}	Signaling rate	0		1000	kbps
V _{IH}	High-level input voltage (IN) (EN on all devices)	2		V _{CC}	V
V _{IL}	Low-level input voltage (IN) (EN on all devices)	0		0.8	V
T _J	Junction temperature			150	°C
H	External magnetic field-strength immunity per IEC 61000-4-8 and IEC 61000-4-9 certification			1000	A/m

- (1) For the 5-V operation, V_{CC1} or V_{CC2} is specified from 4.5 V to 5.5 V.
For the 3-V operation, V_{CC1} or V_{CC2} is specified from 3.15 V to 3.6 V.

ELECTRICAL CHARACTERISTICS: V_{CC1} and V_{CC2} at 5-V⁽¹⁾ OPERATION

, over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I _{CC1}	Quiescent	V _I = V _{CC} or 0 V, All channels, no load, EN ₁ at 3 V, EN ₂ at 3 V		6.5	11	mA
	1 Mbps					
I _{CC2}	Quiescent	V _I = V _{CC} or 0 V, All channels, no load, EN ₁ at 3 V, EN ₂ at 3 V		13	20	mA
	1 Mbps			13	20	
ELECTRICAL CHARACTERISTICS						
I _{OFF}	Sleep mode output current	EN at 0 V, Single channel		0		μA
V _{OH}	High-level output voltage	I _{OH} = −4 mA, See Figure 1	V _{CC} − 0.8			V
		I _{OH} = −20 μA, See Figure 1	V _{CC} − 0.1			
V _{OL}	Low-level output voltage	I _{OL} = 4 mA, See Figure 1			0.4	V
		I _{OL} = 20 μA, See Figure 1			0.1	
V _{I(HYS)}	Input voltage hysteresis			150		mV
I _{IH}	High-level input current	IN from 0 V to V _{CC}			10	μA
I _{IL}	Low-level input current		−10			
C _I	Input capacitance to ground	IN at V _{CC} , V _I = 0.4 sin (4E6πt)		2		pF
CMTI	Common-mode transient immunity	V _I = V _{CC} or 0 V, See Figure 4	25	50		kV/μs

- (1) For the 5-V operation, V_{CC1} or V_{CC2} is specified from 4.5 V to 5.5 V.
For the 3-V operation, V_{CC1} or V_{CC2} is specified from 3.15 V to 3.6 V.

SWITCHING CHARACTERISTICS: V_{CC1} and V_{CC2} at 5-V OPERATION

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH} , t_{PHL}	Propagation delay	See Figure 1	40		95	ns
PWD	Pulse-width distortion ⁽¹⁾ $ t_{PHL} - t_{PLH} $				10	
$t_{sk(o)}$	Channel-to-channel output skew ⁽²⁾				2	ns
t_r	Output signal rise time	See Figure 1		2		ns
t_f	Output signal fall time			2		
t_{PHZ}	Propagation delay, high-level-to-high-impedance output	See Figure 2		15	20	ns
t_{PZH}	Propagation delay, high-impedance-to-high-level output			15	20	
t_{PLZ}	Propagation delay, low-level-to-high-impedance output			15	20	
t_{PZL}	Propagation delay, high-impedance-to-low-level output			15	20	
t_{fs}	Failsafe output delay time from input power loss	See Figure 3		12		μ s

- (1) Also referred to as pulse skew.
(2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

ELECTRICAL CHARACTERISTICS: V_{CC1} at 5-V, V_{CC2} at 3.3-V⁽¹⁾ OPERATION

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SUPPLY CURRENT							
I _{CC1}	Quiescent	V _I = V _{CC} or 0 V, All channels, no load, EN ₁ at 3 V, EN ₂ at 3 V			6.5	11	mA
	1 Mbps						
I _{CC2}	Quiescent	V _I = V _{CC} or 0 V, All channels, no load, EN ₁ at 3 V, EN ₂ at 3 V			8	13	mA
	1 Mbps				8	13	
ELECTRICAL CHARACTERISTICS							
I _{OFF}	Sleep mode output current	EN at 0 V, Single channel		0			μA
V _{OH}	High-level output voltage	I _{OH} = −4 mA, See Figure 1	(5-V side)	V _{CC} − 0.8			V
		I _{OH} = −20 μA, See Figure 1		V _{CC} − 0.1			
V _{OL}	Low-level output voltage	I _{OL} = 4 mA, See Figure 1				0.4	V
		I _{OL} = 20 μA, See Figure 1				0.1	
V _{I(HYS)}	Input voltage hysteresis			150			mV
I _{IH}	High-level input current	IN from 0 V to V _{CC}				10	μA
I _{IL}	Low-level input current			−10			
C _I	Input capacitance to ground	IN at V _{CC} , V _I = 0.4 sin (4E6πt)		2			pF
CMTI	Common-mode transient immunity	V _I = V _{CC} or 0 V, See Figure 4		25	50		kV/μs

- (1) For the 5-V operation, V_{CC1} or V_{CC2} is specified from 4.5 V to 5.5 V.
For the 3-V operation, V_{CC1} or V_{CC2} is specified from 3.15 V to 3.6 V.

SWITCHING CHARACTERISTICS: V_{CC1} at 5-V, V_{CC2} at 3.3-V OPERATION

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH} , t_{PHL}	Propagation delay	See Figure 1	40		100	ns
PWD	Pulse-width distortion ⁽¹⁾ $ t_{PHL} - t_{PLH} $				11	
$t_{sk(o)}$	Channel-to-channel output skew ⁽²⁾				3	ns
t_r	Output signal rise time	See Figure 1		2		ns
t_f	Output signal fall time			2		
t_{PHZ}	Propagation delay, high-level-to-high-impedance output	See Figure 2		15	20	ns
t_{PZH}	Propagation delay, high-impedance-to-high-level output			15	20	
t_{PLZ}	Propagation delay, low-level-to-high-impedance output			15	20	
t_{PZL}	Propagation delay, high-impedance-to-low-level output			15	20	
t_{fs}	Failsafe output delay time from input power loss	See Figure 3		18		μ s

- (1) Also known as pulse skew
(2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

ELECTRICAL CHARACTERISTICS: V_{CC1} at 3.3-V, V_{CC2} at 5-V⁽¹⁾ OPERATION

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SUPPLY CURRENT							
I _{CC1}	Quiescent	V _I = V _{CC} or 0 V, All channels, no load, EN ₁ at 3 V, EN ₂ at 3 V			4	7	mA
	1 Mbps				4	7	
I _{CC2}	Quiescent	V _I = V _{CC} or 0 V, All channels, no load, EN ₁ at 3 V, EN ₂ at 3 V			13	20	mA
	1 Mbps				13	20	
ELECTRICAL CHARACTERISTICS							
I _{OFF}	Sleep mode output current	EN at V _{CC} , Single channel			0		μA
V _{OH}	High-level output voltage	I _{OH} = −4 mA, See Figure 1	(5-V side)		V _{CC} − 0.8		V
		I _{OH} = −20 μA, See Figure 1			V _{CC} − 0.1		
V _{OL}	Low-level output voltage	I _{OL} = 4 mA, See Figure 1			0.4		V
		I _{OL} = 20 μA, See Figure 1			0.1		
V _{I(HYS)}	Input voltage hysteresis				150		mV
I _{IH}	High-level input current	IN from 0 V to V _{CC}			10		μA
I _{IL}	Low-level input current				−10		
C _I	Input capacitance to ground	IN at V _{CC} , V _I = 0.4 sin (4E6πt)			2		pF
CMTI	Common-mode transient immunity	V _I = V _{CC} or 0 V, See Figure 4			25	50	kV/μs

- (1) For the 5-V operation, V_{CC1} or V_{CC2} is specified from 4.5 V to 5.5 V.
 For the 3-V operation, V_{CC1} or V_{CC2} is specified from 3.15 V to 3.6 V.

SWITCHING CHARACTERISTICS: V_{CC1} at 3.3-V and V_{CC2} at 5-V OPERATION

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH} , t_{PHL}	Propagation delay	See Figure 1	40		100	ns
PWD	Pulse-width distortion ⁽¹⁾ $ t_{PHL} - t_{PLH} $				11	
$t_{sk(o)}$	Channel-to-channel output skew ⁽²⁾				2.5	ns
t_r	Output signal rise time	See Figure 1		2		ns
t_f	Output signal fall time			2		
t_{PHZ}	Propagation delay, high-level-to-high-impedance output	See Figure 2		15	20	ns
t_{PZH}	Propagation delay, high-impedance-to-high-level output			15	20	
t_{PLZ}	Propagation delay, low-level-to-high-impedance output			15	20	
t_{PZL}	Propagation delay, high-impedance-to-low-level output			15	20	
t_{fs}	Failsafe output delay time from input power loss	See Figure 3		12		μs

- (1) Also known as pulse skew
 (2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

ELECTRICAL CHARACTERISTICS: V_{CC1} and V_{CC2} at 3.3 V⁽¹⁾ OPERATION

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I _{CC1}	Quiescent	V _I = V _{CC} or 0 V, all channels, no load, EN ₁ at 3 V, EN ₂ at 3 V		4	7	mA
	1 Mbps			4	7	
I _{CC2}	Quiescent	V _I = V _{CC} or 0 V, all channels, no load, EN ₁ at 3 V, EN ₂ at 3 V		8	13	mA
	1 Mbps			8	13	
ELECTRICAL CHARACTERISTICS						
I _{OFF}	Sleep mode output current	EN at 0 V, single channel		0		μA
V _{OH}	High-level output voltage	I _{OH} = −4 mA, See Figure 1		V _{CC} − 0.4		V
		I _{OH} = −20 μA, See Figure 1		V _{CC} − 0.1		
V _{OL}	Low-level output voltage	I _{OL} = 4 mA, See Figure 1			0.4	V
		I _{OL} = 20 μA, See Figure 1			0.1	
V _{I(HYS)}	Input voltage hysteresis			150		mV
I _{IH}	High-level input current	IN from 0 V or V _{CC}			10	μA
I _{IL}	Low-level input current			−10		
C _I	Input capacitance to ground	IN at V _{CC} , V _I = 0.4 sin (4E6πt)		2		pF
CMTI	Common-mode transient immunity	V _I = V _{CC} or 0 V, See Figure 4	25	50		kV/μs

- (1) For the 5-V operation, V_{CC1} or V_{CC2} is specified from 4.5 V to 5.5 V.
For the 3-V operation, V_{CC1} or V_{CC2} is specified from 3.15 V to 3.6 V.

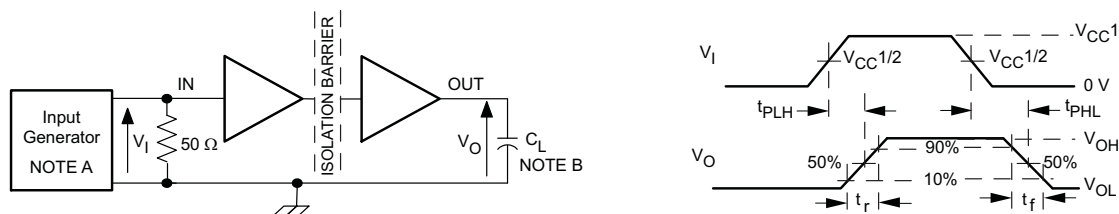
SWITCHING CHARACTERISTICS: V_{CC1} and V_{CC2} at 3.3-V OPERATION

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH} , t_{PHL}	Propagation delay	See Figure 1	45		110	ns
PWD	Pulse-width distortion $ t_{PHL} - t_{PLH} $ ⁽¹⁾				12	
$t_{sk(o)}$	Channel-to-channel output skew ⁽²⁾				3.5	ns
t_r	Output signal rise time	See Figure 1		2		
t_f	Output signal fall time			2		
t_{PHZ}	Propagation delay, high-level-to-high-impedance output	See Figure 2		15	20	ns
t_{PZH}	Propagation delay, high-impedance-to-high-level output			15	20	
t_{PLZ}	Propagation delay, low-level-to-high-impedance output			15	20	
t_{PZL}	Propagation delay, high-impedance-to-low-level output			15	20	
t_{fs}	Failsafe output delay time from input power loss	See Figure 3		18		μ s

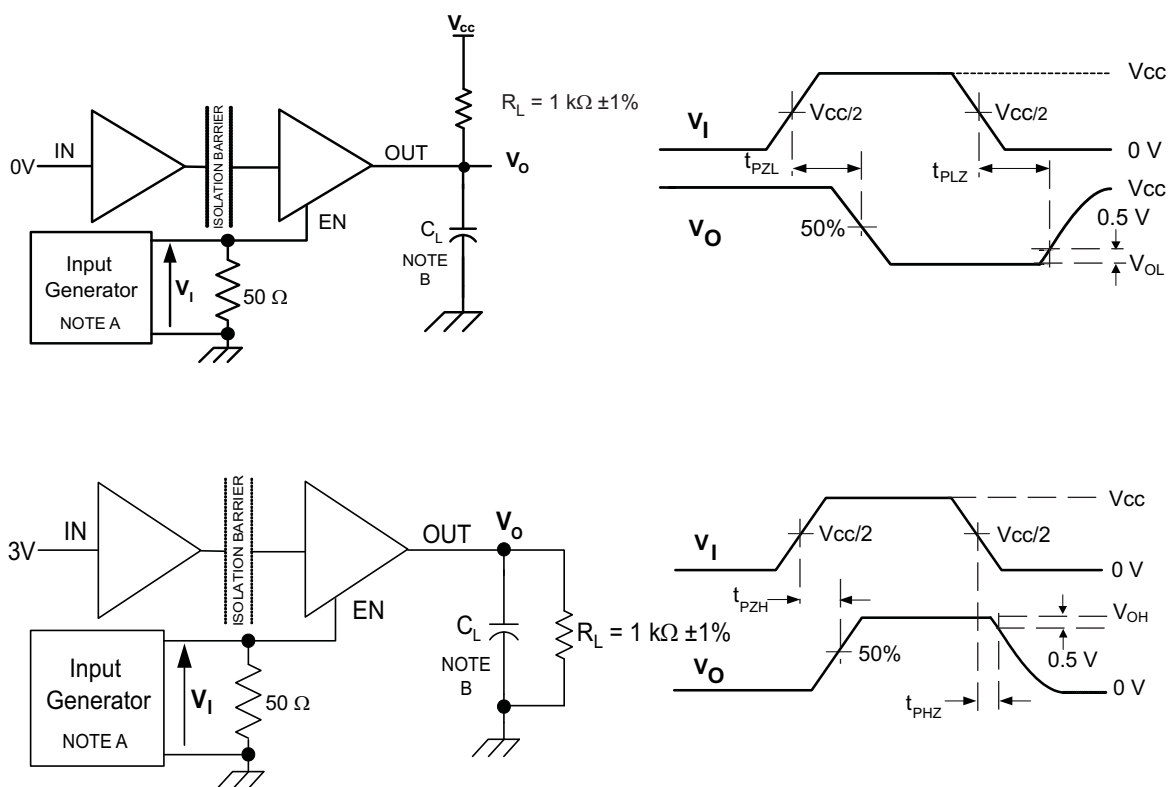
- (1) Also referred to as pulse skew.
(2) $t_{sk(o)}$ is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

PARAMETER MEASUREMENT INFORMATION



- The input pulse is supplied by a generator having the following characteristics: $PRR \leq 50 \text{ kHz}$, 50% duty cycle, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$, $Z_O = 50 \Omega$.
- $C_L = 15 \text{ pF}$ and includes instrumentation and fixture capacitance within $\pm 20\%$.

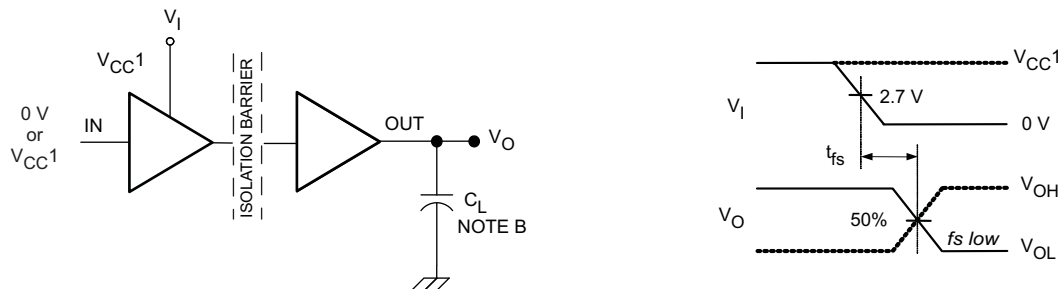
Figure 1. Switching Characteristic Test Circuit and Voltage Waveforms



- The input pulse is supplied by a generator having the following characteristics: $PRR \leq 50 \text{ kHz}$, 50% duty cycle, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$, $Z_O = 50 \Omega$.
- $C_L = 15 \text{ pF}$ and includes instrumentation and fixture capacitance within $\pm 20\%$.

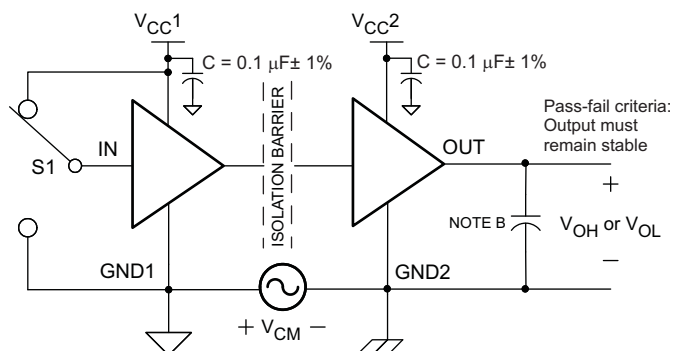
Figure 2. Enable/Disable Propagation Delay Time Test Circuit and Waveform

PARAMETER MEASUREMENT INFORMATION (continued)



- A. $C_L = 15 \text{ pF}$ and includes instrumentation and fixture capacitance within $\pm 20\%$.
- B. The input pulse is supplied by a generator having the following characteristics: $\text{PRR} \leq 50 \text{ kHz}$, 50% duty cycle, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$, $Z_O = 50 \Omega$.

Figure 3. Failsafe Delay Time Test Circuit and Voltage Waveforms



- A. $C_L = 15 \text{ pF}$ and includes instrumentation and fixture capacitance within $\pm 20\%$.
- B. The input pulse is supplied by a generator having the following characteristics: $\text{PRR} \leq 50 \text{ kHz}$, 50% duty cycle, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$, $Z_O = 50 \Omega$.

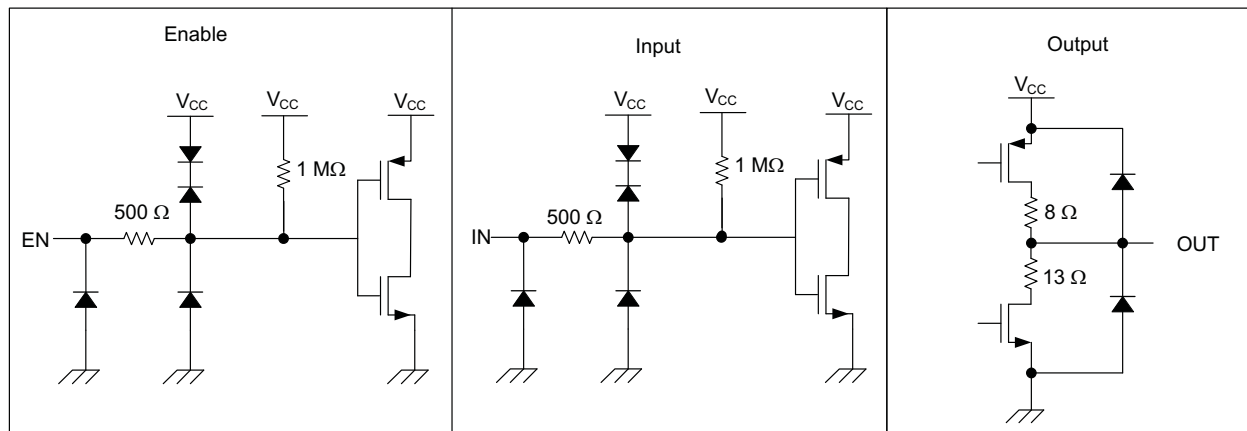
Figure 4. Common-Mode Transient Immunity Test Circuit and Voltage Waveform

DEVICE INFORMATION

PACKAGE CHARACTERISTICS

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
L(I01) Minimum air gap (Clearance)	Shortest terminal-to-terminal distance through air	8.34			mm
L(I02) Minimum external tracking (Creepage)	Shortest terminal-to-terminal distance across the package surface	8.1			mm
Minimum Internal Gap (Internal Clearance)	Distance through the insulation	0.008			mm
R _{IO} Isolation resistance	Input to output, V _{IO} = 500 V, all pins on each side of the barrier tied together creating a two-terminal device	>10 ¹²			Ω
C _{IO} Barrier capacitance Input to output	V _I = 0.4 sin (4E6πt)		2		pF
C _I Input capacitance to ground	V _I = 0.4 sin (4E6πt)		2		pF

DEVICE I/O SCHEMATICS



REGULATORY INFORMATION

VDE	CSA	UL
Certified according to IEC 60747-5-2	Approved under CSA Component Acceptance Notice	Recognized under 1577 Component Recognition Program ⁽¹⁾
File Number: 40016131	File Number: 1698195	File Number: E181974

(1) Production tested ≥ 3000 Vrms for 1 second in accordance with UL 1577.

THERMAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
θ _{JA} Junction-to-air	Low-K Thermal Resistance ⁽¹⁾		168		°C/W
	High-K Thermal Resistance		96.1		
θ _{JB} Junction-to-Board Thermal Resistance			61		°C/W
θ _{JC} Junction-to-Case Thermal Resistance			48		°C/W
P _D Device Power Dissipation	V _{CC1} = V _{CC2} = 5.5 V, T _J = 150°C, C _L = 15 pF, Input a 50% duty cycle square wave			220	mW

(1) Tested in accordance with the Low-K or High-K thermal metric definitions of EIA/JESD51-3 for leaded surface mount packages.

TYPICAL CHARACTERISTIC CURVES

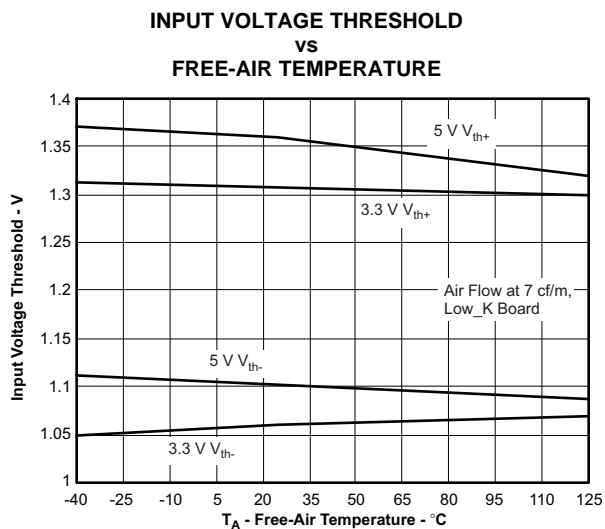


Figure 5.

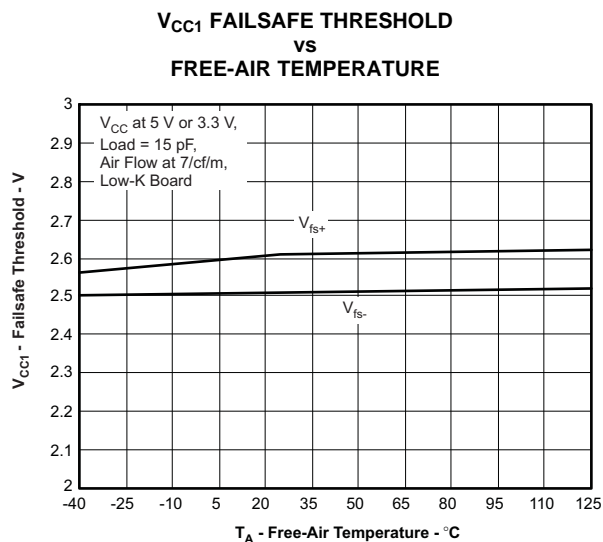


Figure 6.

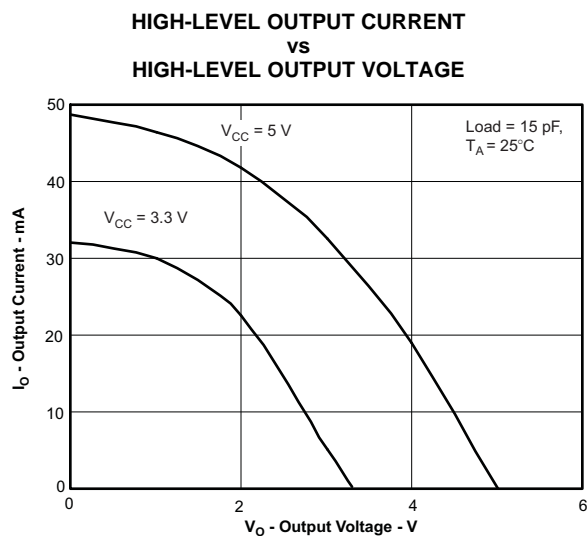


Figure 7.

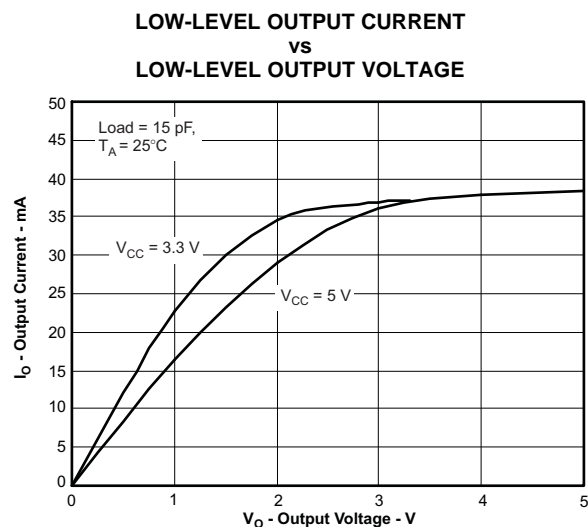


Figure 8.

APPLICATION INFORMATION

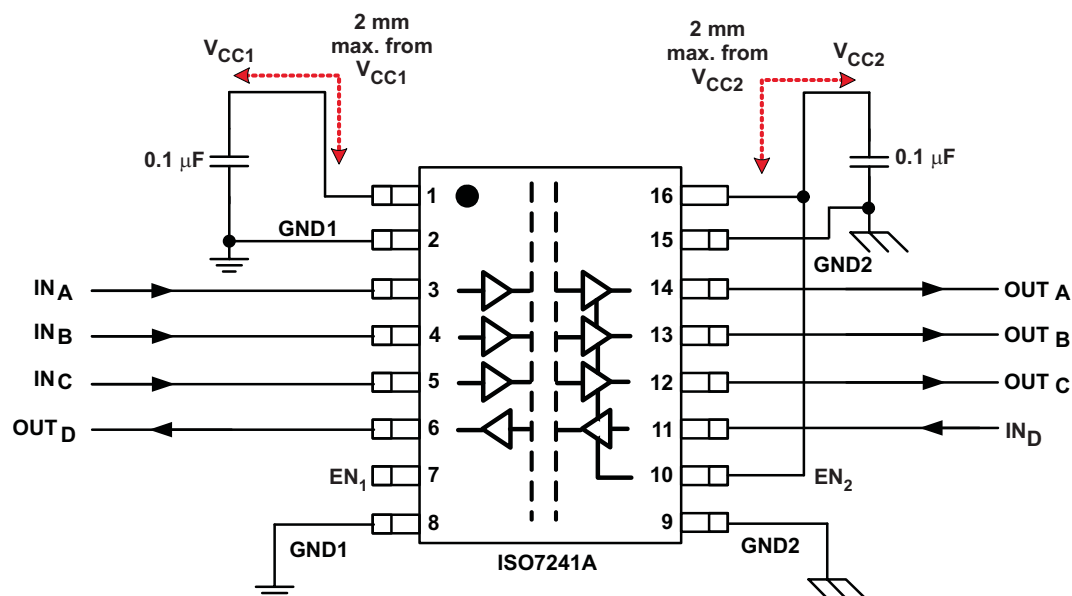


Figure 9. Typical Application Circuit

LIFE EXPECTANCY vs. WORKING VOLTAGE

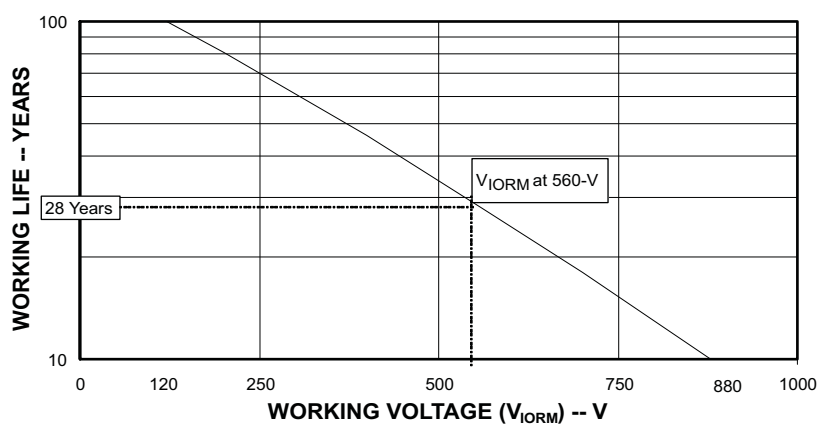


Figure 10. Time-Dependant Dielectric Breakdown Testing Results

PRODUCT NOTIFICATION

An ISO7241A anomaly occurs when a negative-going pulse below the specified 1- μ s minimum bit width is input to the device. The output locks in a logic-low condition until the next rising edge occurs after a 1- μ s period.

Positive noise edges in pulses of less than the minimum specified 1 μ s have no effect on the device, and are properly filtered.

To prevent noise from interfering with ISO7241A performance, it is recommended that an appropriately sized capacitor be placed on each input of the device

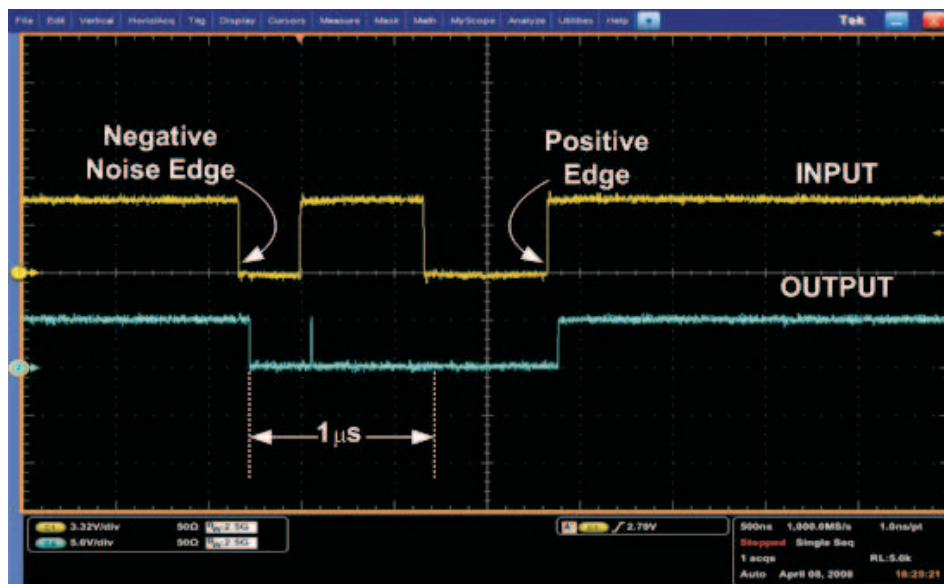


Figure 11. ISO7241A Anomaly

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ISO7241AMDWREP	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-3-260C-168 HR	-55 to 125	ISO7241AM	Samples
V62/10606-01XE	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-3-260C-168 HR	-55 to 125	ISO7241AM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF ISO7241A-EP :

- Catalog: [ISO7241A](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ISO7241AMDWREP	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ISO7241AMDWREP	SOIC	DW	16	2000	350.0	350.0	43.0

GENERIC PACKAGE VIEW

DW 16

SOIC - 2.65 mm max height

7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224780/A



DW0016B

PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



4221009/B 07/2016

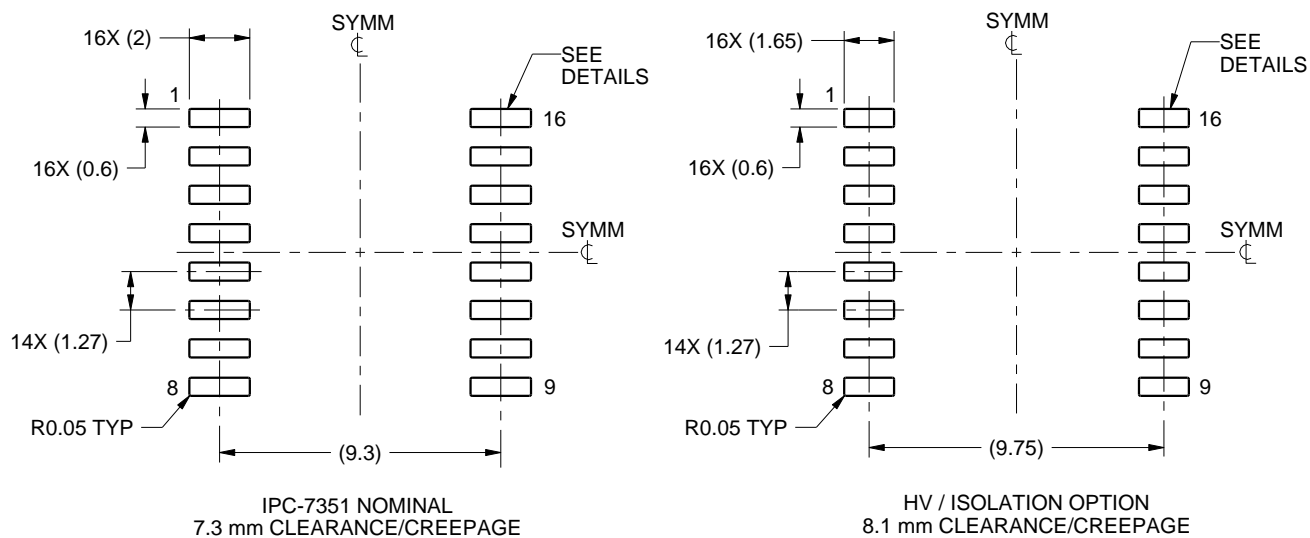
NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

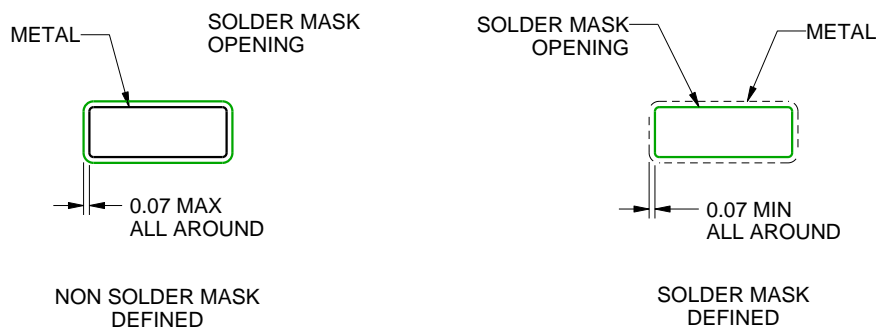
DW0016B

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:4X



SOLDER MASK DETAILS

4221009/B 07/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0016B

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:4X

4221009/B 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2020, Texas Instruments Incorporated